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TABLE OF CONTENTS

PART 1

EDITORIAL TO THE PROCEEDINGS OF THE 6TH INTERNATIONAL CONFERENCE ON CRYSTALLINE SILICON PHOTOVOLTAICS (SILICONPV 2016)	1
<i>Pierre-Jean Ribeyron</i>	

ADVANCED CHARACTERIZATION AND SIMULATION

ON THE VARIABILITY OF THE TEMPERATURE COEFFICIENTS OF MC-SI SOLAR CELLS WITH IRRADIANCE	2
<i>Charly Berthod, Rune Strandberg, Georgi H. Yordanov, Hans G. Beyer, Jan O. Odden</i>	
LOCAL SOLAR CELL EFFICIENCY ANALYSIS PERFORMED BY INJECTION-DEPENDENT PL IMAGING (ELBA) AND VOLTAGE-DEPENDENT LOCK-IN THERMOGRAPHY (LOCAL I-V)	10
<i>Otwin Breitenstein, Felix Frühauf, Jan Bauer, Florian Schindler, Bernhard Michl</i>	
EFFECTIVE SURFACE RECOMBINATION OF P+ LAYERS DOPED USING ION IMPLANTATION OR SURFACE DEPOSITED B SOURCES	16
<i>Ygal Eisenberg, Lev Kreinin, Ninel Bordin, Naftali Eisenberg</i>	
LAPLACIAN PL IMAGE EVALUATION IMPLYING CORRECTION OF PHOTON SCATTERING IN THE LUMINESCENCE DETECTOR	24
<i>Felix Frühauf, Otwin Breitenstein</i>	
LIFETIME ANALYSIS FOR DEFECT CHARACTERIZATION IN KERFLESS EPITAXIAL SILICON FROM THE POROUS SILICON PROCESS	29
<i>Catherin Gemmel, Jan Hensen, Sarah Kajari-Schröder, Rolf Brendel</i>	
QUANTIFICATION OF VOID DEFECTS ON PERC SOLAR CELL REAR CONTACTS	37
<i>Stephan Großer, Sina Swatek, Jonas Pantzer, Marko Turek, Christian Hagendorf</i>	
MODELLING KINETICS OF THE BORON-OXYGEN DEFECT SYSTEM	42
<i>Brett Hallam, Malcolm Abbott, Jose Bilbao, Phill Hamer, Nicholas Gorman, Moonyong Kim, Daniel Chen, Katherine Hammerton, David Payne, Catherine Chan, Nitin Nampalli, Stuart Wenham</i>	
OPTIMIZED TAB WIDTH IN HALF-CELL MODULES	52
<i>Hamed Hanifi, David Dassler, Jens Schneider, Marko Turek, Sebastian Schindler, Joerg Bagdahn</i>	
PC1DMOD 6.2 – IMPROVED SIMULATION OF C-SI DEVICES WITH UPDATES ON DEVICE PHYSICS AND USER INTERFACE	60
<i>Halvard Haug, Johannes Greulich</i>	
SIMULATING THE EFFECT OF LIFETIME NON-UNIFORMITY ON SOLAR CELL PERFORMANCE USING CMD-PC1D 6 AND GRIDDLER 2	69
<i>Halvard Haug, Marie Syre Wiig, Rune Søndena, Johnson Wong</i>	
FINITE ELEMENT SIMULATION OF THE LOCAL AL/SI CONTACT FORMATION	75
<i>Axel Herguth</i>	
SURFACE RECOMBINATION VELOCITY OF LOCAL AL-CONTACTS OF PERC SOLAR CELLS DETERMINED FROM LBIC MEASUREMENTS AND 2D SIMULATION	82
<i>Renate Horbelt, Gabriel Micard, Philipp Keller, Reinhart Job, Giso Hahn, Barbara Terheiden</i>	
EXTRACTION OF RECOMBINATION PROPERTIES FROM LIFETIME DATA	88
<i>Gaby J. M. Janssen, Yu Wu, Kees C. J. J. Tool, Ingrid G. Romijn, Andreas Fell</i>	
EFFICIENCY IMPROVEMENT BY CHARGED-INSULATOR LAYERS FOR IBC-SHJ CELLS	96
<i>Takefumi Kamioka, Yutaka Hayashi, Kyotaro Nakamura, Yoshio Ohshita</i>	
INFLUENCE OF THE DOPANT PENETRATION DEPTH ON THE SOLAR CELL PERFORMANCE OF N-TYPE INTERDIGITATED BACK CONTACT SILICON SOLAR CELLS	103
<i>Alexander V. Korovin, José Alvarez, Jean-Paul Kleider</i>	
SIMULATION-BASED EFFICIENCY GAIN ANALYSIS OF 21.2%-EFFICIENT SCREEN-PRINTED PERC SOLAR CELLS	109
<i>Christopher Kranz, Jan H. Petermann, Thorsten Dullweber, Rolf Brendel</i>	
STUDY OF PINHOLE CONDUCTIVITY AT PASSIVATED CARRIER-SELECTED CONTACTS OF SILICON SOLAR CELLS	116
<i>Kevin Lancaster, Stephan Großer, Frank Feldmann, Volker Naumann, Christian Hagendorf</i>	
RAY TRACING ISOTEXTURED SOLAR CELLS	122
<i>Keith R. McIntosh, Malcolm D. Abbott, Ben A. Sudbury</i>	

DEFECTS IN MULTICRYSTALLINE SI WAFERS STUDIED BY SPECTRAL PHOTOLUMINESCENCE IMAGING, COMBINED WITH EBSD AND DISLOCATION MAPPING	130
<i>Torbjørn Mehl, Marisa Di Sabatino, Krzysztof Adamczyk, Ingunn Burud, Espen Olsen</i>	
REPORTING EFFECTIVE LIFETIMES AT SOLAR CELL RELEVANT INJECTION DENSITIES	138
<i>Matthias Müller</i>	
EVALUATING DEPTH DISTRIBUTIONS OF DISLOCATIONS IN SILICON WAFERS USING MICRO-PHOTOLUMINESCENCE EXCITATION SPECTROSCOPY	145
<i>Hieu T. Nguyen, Sieu Pheng Phang, Daniel Macdonald</i>	
SIMULATION STUDY OF LIGHT-INDUCED, CURRENT-INDUCED DEGRADATION AND RECOVERY ON PERC SOLAR CELLS	153
<i>Massimo Nicolai, Mauro Zanucoli, Marco Galiazzo, Matteo Bertazzo, Enrico Sangiorgi, Claudio Fiegna</i>	
NUMERICAL SIMULATION AND EXPERIMENTAL CHARACTERIZATION OF EMITTER WRAP THROUGH SOLAR CELLS WITH DEEP GROOVED BASE CONTACT (EWT-DGB)	160
<i>Massimo Nicolai, Mauro Zanucoli, Giovanni Paternoster, Giuseppe De Ceglia, Lorenza Ferrario, Pierluigi Bellutti, Enrico Sangiorgi, Claudio Fiegna</i>	
A UNIFIED PARAMETERIZATION OF THE FORMATION OF BORON OXYGEN DEFECTS AND THEIR ELECTRICAL ACTIVITY	170
<i>Tim Niewelt, Jonas Schön, Juliane Broisch, Sven Mägdefessel, Wilhelm Warta, Martin C. Schubert</i>	
TEMPERATURE DEPENDENT LIFETIME SPECTROSCOPY (TDLS) FOR THE IDENTIFICATION OF METALLIC IMPURITIES	180
<i>Etienne Quiniou, Olivier Palais, Damien Barakel, Isabelle Périchaud</i>	
BIFACIAL PHOTOVOLTAIC MODULES: MEASUREMENT CHALLENGES	188
<i>Guillaume Razongles, Lionel Sicot, Maryline Joanny, Eric Gerritsen, Paul Lefillastre, Silke Schroder, Philippe Lay</i>	
PARASITIC ABSORPTION IN POLYCRYSTALLINE SI-LAYERS FOR CARRIER-SELECTIVE FRONT JUNCTIONS	199
<i>Sina Reiter, Nico Koper, Rolf Reineke-Koch, Yevgeniya Larionova, Mircea Turcu, Jan Krügener, Dominic Tetzlaff, Tobias Wietler, Uwe Höhne, Jan-Dirk Kähler, Rolf Brendel, Robby Peibst</i>	
SOLAR SIMULATOR SPECTRUM AND MEASUREMENT UNCERTAINTIES	205
<i>Felix Schubert, Daniel Spinner</i>	
INSTABILITY OF DIELECTRIC SURFACE PASSIVATION QUALITY AT ELEVATED TEMPERATURE AND ILLUMINATION	211
<i>David Sperber, Axel Herguth, Giso Hahn</i>	
HIGH RESOLUTION SHEET RESISTANCE MAPPING TO UNVEIL EDGE EFFECTS IN INDUSTRIAL IBC SOLAR CELLS	218
<i>Pierpaolo Spinelli, Pi Danzl, Nicolas Guillevin, Agnes Mewe, Simon Sawallich, Ard Vlooswijk, Bas Van De Loo, Erwin Kessels, Michael Nagel, Ilkay Cesar</i>	
CHOOSING THE BEST SILICON MATERIAL PARAMETERS FOR DIFFERENT SOLAR CELL ARCHITECTURES	225
<i>Heiko Steinkemper, Bernhard Michl, Martin Hermle, Stefan W. Glunz</i>	
IDENTIFICATION AND CLASSIFICATION OF CONTAMINATIONS ON WAFERS USING HYPERSPECTRAL IMAGING	232
<i>Marko Turek, Andreas Backhaus, Sylke Meyer, Udo Seiffert</i>	
INFLUENCE OF SILVER-ALUMINIUM ALLOY AT SOLAR CELL REAR SIDE ON SERIES RESISTANCE AND OPEN CIRCUIT VOLTAGE	236
<i>Tobias Urban, Ansgar Mette, Johannes Heitmann</i>	
MANUFACTURING AND CHARACTERIZATION OF III-V ON SILICON MULTI-JUNCTION SOLAR CELLS	242
<i>Elias Veinberg-Vidal, Cécilia Dupré, Pablo Garcia-Linares, Christophe Jany, Romain Thibon, Tiphaine Card, Thierry Salvetat, Pascal Scheiblin, Céline Brughera, Frank Fournel, Yohan Desieres, Yannick Veschetti, Vincent Sanzone, Pierre Mur, Jean Decobert, Alejandro Datas</i>	
CARRIER LIFETIME IN LIQUID-PHASE CRYSTALLIZED SILICON ON GLASS	248
<i>Michael Vetter, Annett Gawlik, Jonathan Plentz, Gudrun Andrä</i>	
LINEAR-RESPONSE DESCRIPTION OF THE SERIES RESISTANCE OF LARGE-AREA SILICON SOLAR CELLS: RESOLVING THE DIFFERENCE BETWEEN DARK AND ILLUMINATED BEHAVIOR	255
<i>Jan-Martin Wagner, Andreas Schütt, Jürgen Carstensen, Rainer Adelung</i>	
INJECTION-DEPENDENT CARRIER LIFETIME ANALYSIS OF RECOMBINATION DUE TO BORON-OXYGEN COMPLEXES IN WAFERS PASSIVATED WITH DIFFERENT DIELECTRICS BY QSSPL AND QSSPC	265
<i>Xi Wang, Mattias Juhl, Alison Lennon</i>	

WAFER FTIR - MEASURING INTERSTITIAL OXYGEN ON AS CUT AND PROCESSED SILICON WAFERS	274
<i>Franziska Wolny, Andreas Krause, Alexander Oehlke, Matthias Wagner</i>	
MAJORITY CARRIER MOBILITY OF COMPENSATED SILICON: COMPARISON OF ROOM TEMPERATURE MEASUREMENTS AND MODELS	278
<i>Song Zhang, Chiara Modanese, Guilherme Gaspar, Rune Søndena, Gabriella Tranell, Marisa Di Sabatino</i>	

ADVANCED LIGHT MANAGEMENT

IMPROVED LIGHT MANAGEMENT IN SILICON HETEROJUNCTION SOLAR CELLS BY APPLICATION OF A ZNO NANOROD ANTIREFLECTIVE LAYER	284
<i>Maike Ahrlich, Oleg Sergeev, Maren Juilfs, Alex Neumüller, Martin Vehse, Carsten Agert</i>	
LIGHT TRAPPING BY MICRO AND NANO-HOLE TEXTURING OF SINGLE-CRYSTALLINE SILICON SOLAR CELLS	291
<i>Serra H. Altinoluk, Hande E. Ciftinar, Olgu Demircioglu, Firat Es, Gulsen Baytemir, Orhan Akar, Akin Aydemir, Adem Sarac, Tayfun Akin, Rasit Turan</i>	
HIGH-MOBILITY HYDROGENATED INDIUM OXIDE WITHOUT INTRODUCING WATER DURING SPUTTERING	297
<i>Mathieu Boccard, Nathan Rodkey, Zachary C. Holman</i>	

CLEANING, ETCHING, SURFACE MORPHOLOGY AND ASSOCIATED PASSIVATION

SILICON SURFACE PASSIVATION BY MIXED ALUMINUM PRECURSORS IN AL₂O₃ ATOMIC LAYER DEPOSITION	304
<i>Yameng Bao, Haibing Huang, Zhen Zhu, Jun Lv, Hele Savin</i>	
INFLUENCE OF THE DISCHARGE MODE ON THE OPTICAL AND PASSIVATION PROPERTIES OF SiN_x:H DEPOSITED BY PECVD AT ATMOSPHERIC PRESSURE	309
<i>Rémy Bazinette, Jean-François Lelièvre, Laura Gaudy, Françoise Massines</i>	
IMPROVED SILICON SURFACE PASSIVATION OF APCVD AL₂O₃ BY RAPID THERMAL ANNEALING	317
<i>Lachlan E. Black, Thomas Allen, Keith R. McIntosh, Andres Cuévas</i>	
CORONA CHARGE IN SiO₂: KINETICS AND SURFACE PASSIVATION FOR HIGH EFFICIENCY SILICON SOLAR CELLS	326
<i>Ruy S. Bonilla, Nicolas Jennison, Deborah Clayton-Warwick, Katherine A. Collett, Lucy Rands, Peter R. Wilshaw</i>	
CORONA FIELD EFFECT SURFACE PASSIVATION OF N-TYPE IBC CELLS	336
<i>Ruy S. Bonilla, Christian Reichel, Martin Hermle, Peter R. Wilshaw</i>	
LONG-TERM STABILITY OF AL₂O₃ PASSIVATED BLACK SILICON	341
<i>Eric Calle, Pablo Ortega, Guillaume Von Gastrow, Isidro Martín, Hele Savin, Ramón Alcubilla</i>	
DOUBLE LAYERS OF ULTRATHIN A-SI:H AND SiN_x FOR SURFACE PASSIVATION OF N-TYPE CRYSTALLINE SI WAFERS	347
<i>Xuemei Cheng, Erik Stensrud Marstein, Halvard Haug, Marisa Di Sabatino</i>	
THERMAL TREATMENT EFFECTS ON FLAT-BAND VOLTAGE SHIFT IN ATOMIC-LAYER-DEPOSITED ALUMINA OR ALUMINUM OXIDE/SILICON NITRIDE PASSIVATION STACKS	353
<i>Supawan Joonwichien, Shalamujiang Simayi, Katsuhiko Shirasawa, Katsuto Tanahashi, Hidetaka Takato</i>	
PLASMA-FREE DRY-CHEMICAL TEXTURING PROCESS FOR HIGH-EFFICIENCY MULTICRYSTALLINE SILICON SOLAR CELLS	359
<i>Bishal Kafle, Timo Freund, Abdul Mannan, Laurent Clochard, Edward Duffy, Sabrina Werner, Pierre Saint-Cast, Marc Hofmann, Jochen Rentsch, Ralf Preu</i>	
ADVANCED METAL CONTAMINATION ANALYSIS FOR HIGH EFFICIENCY SOLAR CELL MANUFACTURING	369
<i>Sylke Meyer, Stefanie Wahl, Christian Hagendorf</i>	
OZONE-BASED SURFACE CONDITIONING FOCUSED ON AN IMPROVED PASSIVATION FOR SILICON HETEROJUNCTION SOLAR CELLS	374
<i>Anamaria Moldovan, Tobias Dannenberg, Jan Temmler, Laurent Kroely, Martin Zimmer, Jochen Rentsch</i>	
EFFECT OF DIFFERENT ALD AL₂O₃ OXIDANTS ON THE SURFACE PASSIVATION OF BLACK SILICON	381
<i>Päivikki Repo, Hele Savin</i>	
EFFECT OF DIAMOND WIRE SAW MARKS ON SOLAR CELL PERFORMANCE	386
<i>Hubert Seigneur, Eric J. Schneller, Narendra S. Shiradkar, Winston V. Schoenfeld</i>	

LOCALIZATION OF INORGANIC IMPURITIES IN SILICON SAMPLES BY SEQUENTIAL ETCHING AND ICP-MS DETECTION	392
<i>Stefanie Wahl, Sylke Meyer, Christian Hagendorf</i>	

HIGH EFFICIENCY DEVICES

22.2% EFFICIENCY N-TYPE PERT SOLAR CELL	399
<i>Wenhao Cai, Shengzhao Yuan, Yun Sheng, Weiyuan Duan, Zigang Wang, Yifeng Chen, Yang Yang, Pietro. P. Altermatt, Pierre J. Verlinden, Zhiqiang Feng</i>	
INVESTIGATION OF REAR LOCALIZED BACK SURFACE FIELD FORMED FROM BORON LASER DOPING AND SCREEN-PRINTED ALUMINUM PASTE IN HIGH-EFFICIENCY SOLAR CELLS	404
<i>Yoshinori Ikeda, Yuka Tomizawa, Haruhiko Itoh, Takashi Shiro</i>	
RECOMBINATION BEHAVIOR OF PHOTOLITHOGRAPHY-FREE BACK JUNCTION BACK CONTACT SOLAR CELLS WITH CARRIER-SELECTIVE POLYSILICON ON OXIDE JUNCTIONS FOR BOTH POLARITIES	412
<i>Michael Rienäcker, Agnes Merkle, Udo Römer, Heike Kohlenberg, Jan Krügener, Rolf Brendel, Robby Peibst</i>	
DEVELOPMENT OF N-TYPE SELECTIVE EMITTER SILICON SOLAR CELLS BY LASER DOPING USING BORON-DOPED SILICON PASTE	419
<i>Yuka Tomizawa, Yoshinori Ikeda, Takashi Shiro</i>	
IN-SITU DOPING AND LOCAL OVERCOMPENSATION OF HIGH PERFORMANCE LPCVD POLYSILICON PASSIVATED CONTACTS AS APPROACH TO INDUSTRIAL IBC CELLS	427
<i>Yu Wu, Maciej K. Stodolny, L. J. Geerligs, Martijn Lenes, Jan-Marc Luchies</i>	
SIMULATION OF 20.96% EFFICIENCY N-TYPE CZOCHRALSKI UMG SILICON SOLAR CELL	434
<i>Peiting Zheng, Fiacre E. Rougieux, Chris Samundsett, Xinbo Yang, Yimao Wan, Julien Degoulange, Roland Einhaus, Pascal Rivat, Daniel Macdonald</i>	

JUNCTION FORMATION

ATOMIC LAYER DEPOSITED MOLYBDENUM OXIDE FOR THE HOLE-SELECTIVE CONTACT OF SILICON SOLAR CELLS	443
<i>Martin Bivour, Bart Macco, Jan Temmler, W. M. M. (Erwin) Kessels, Martin Hermle</i>	
OPTIMIZED LASER DOPED BACK SURFACE FIELD FOR IBC SOLAR CELLS	450
<i>Morris Dahlinger, Kai Carstens</i>	
ENHANCED OXIDATION OF THERMALLY GROWN SiO₂ DUE TO P PRECIPITATES	457
<i>Amir Dastgheib-Shirazi, Johannes Rinder, Gabriel Micard, Michael Steyer, Giso Hahn, Barbara Terheiden</i>	
LOW TEMPERATURE THERMAL TREATMENTS FOR N-TYPE EMITTERS ON SI SOLAR CELLS	466
<i>Hongzhao Li, Malcolm Abbott, Brett Hallam, Stuart Wenham</i>	
OPTIMIZATION OF BORON DIFFUSION FOR SCREEN PRINTED N-PERT SOLAR CELLS	474
<i>Barbora Mojrová, Corrado Comparotto, Radovan Kopecek, Valentin D. Mihailetchi</i>	
INFLUENCE OF THE BCL₃ DIFFUSION PROCESS HOMOGENEITY ON THE SURFACE PASSIVATION OF N-TYPE PERT SOLAR CELLS	479
<i>Remi Monna, Vincent Sanzone, Julien Diaz, Yannick Veschetti</i>	
CVD BORON CONTAINING GLASSES – AN ATTRACTIVE ALTERNATIVE DIFFUSION SOURCE FOR HIGH QUALITY EMITTERS AND SIMPLIFIED PROCESSING - A REVIEW	486
<i>Barbara Terheiden</i>	

PART 2

MODULE PROCESSING AND MATERIALS

FLEXIBLE MODULES USING <70 μM THICK SILICON SOLAR CELLS	493
<i>André Augusto, Kevin Tyler, Stanislau Y. Herasimenka, Stuart G. Bowden</i>	
THE IMPACT OF RIBBON PROPERTIES ON MEASURED PEEL FORCES	500
<i>Ulrich Eitner, Li C. Rendler</i>	

INCREASED LIGHT HARVESTING BY STRUCTURED CELL INTERCONNECTION RIBBONS: AN OPTICAL RAY TRACING STUDY USING A REALISTIC DAYLIGHT MODEL	505
<i>Hendrik Holst, Henning Schulte-Huxel, Matthias Winter, Susanne Blankemeyer, Robert Witteck, Malte R. Vogt, Thomas Booz, Fabian Distelrath, Marc Köntges, Karsten Bothe, Rolf Brendel</i>	
SIMULTANEOUS CONTACTING AND INTERCONNECTION OF PASSIVATED EMITTER AND REAR SOLAR CELLS.....	515
<i>Henning Schulte-Huxel, Jan-Hendrik Petermann, Susanne Blankemeyer, Verena Steckenreiter, Sarah Kajari-Schroeder, Rolf Brendel</i>	
OPTICAL CONSTANTS OF UV TRANSPARENT EVA AND THE IMPACT ON THE PV MODULE OUTPUT POWER UNDER REALISTIC IRRADIATION.....	523
<i>Malte R. Vogt, Hendrik Holst, Henning Schulte-Huxel, Susanne Blankemeyer, Robert Witteck, David Hinken, Matthias Winter, Byungsul Min, Carsten Schinke, Ingo Ahrens, Marc Köntges, Karsten Bothe, Rolf Brendel</i>	
OPTIMIZING THE SOLAR CELL FRONT SIDE METALLIZATION AND THE CELL INTERCONNECTION FOR HIGH MODULE POWER OUTPUT	531
<i>Robert Witteck, Henning Schulte-Huxel, Hendrik Holst, David Hinken, Malte Vogt, Susanne Blankemeyer, Marc Köntges, Karsten Bothe, Rolf Brendel</i>	

MODULE RELIABILITY AND PRODUCTION YIELD

SHADE PERFORMANCE OF A BACK-CONTACT MODULE ASSEMBLED WITH CELLS FEATURING SOFT BREAKDOWN CHARACTERISTIC	540
<i>Hai Feng Chu, Andreas Halm, Valentin D. Mihailetchi, Giuseppe Galbiati, Radovan Kopecek</i>	
COMPARISON OF GROUND-BASED AND SATELLITE-BASED IRRADIANCE DATA FOR PHOTOVOLTAIC YIELD ESTIMATION	546
<i>Marco Ernst, Andrew Thomson, Ingrid Haedrich, Andrew Blakers</i>	
UNDERSTANDING THE MOVEMENT OF CRACKED SOLAR CELL PARTS IN PV-MODULES DURING MECHANICAL LOADING	554
<i>Felix Haase, Jörg Käsewieder, Marc Köntges</i>	
MICROSTRUCTURAL OPTIMIZATION APPROACH OF SOLAR CELL INTERCONNECTORS FATIGUE BEHAVIOR FOR ENHANCED MODULE LIFETIME IN EXTREME CLIMATES.....	560
<i>Rico Meier, Matthias Pander, Stephan Großer, Sascha Dietrich</i>	
INVESTIGATIONS ON THE FORMATION OF STACKING FAULT-LIKE PID-SHUNTS	569
<i>Volker Naumann, Carlo Brzuska, Martina Werner, Stephan Großer, Christian Hagendorf</i>	
AN ELECTRIC MODEL OF CRACKED SOLAR CELLS ACCOUNTING FOR DISTRIBUTED DAMAGE CAUSED BY CRACK INTERACTION	576
<i>Marco Paggi, Irene Berardone, Marco Martire</i>	
EFFECT OF SOILING ON PHOTOVOLTAIC MODULES IN NORWAY.....	585
<i>Helene Pedersen, Johann Strauss, Josefina Selj</i>	
ANTI-REFLECTIVE COATED GLASS AND ITS IMPACT ON BIFACIAL MODULES' TEMPERATURE IN DESERT LOCATIONS	590
<i>Jorge Rabanal-Arabach, Andreas Schneider</i>	
MODELLING OF BIFACIAL GAIN FOR STAND-ALONE AND IN-FIELD INSTALLED BIFACIAL PV MODULES	600
<i>Ismail Shoukry, Joris Libal, Radovan Kopecek, Eckard Wefringhaus, Jürgen Werner</i>	
PID- AND UVID-FREE N-TYPE SOLAR CELLS AND MODULES.....	609
<i>Maciej K. Stodolny, Gaby J. M. Janssen, Bas B. Van Aken, Kees C. J. J. Tool, Machteld W. P. E. Lamers, Ingrid G. Romijn, Peter R. Venema, Marten R. Renes, Olga Starheyeva, Ernst H. A. Granneman, Jianming Wang, Jikui Ma, Jingguang Cui, Fang Lang, Zhiyan Hu, Jochen Löffler</i>	

NOVEL CELL STRUCTURES, E.G. APPLYING TANDEM, NEW MATERIAL COMBINATIONS OR NANOSTRUCTURES

SILICON MINORITY-CARRIER LIFETIME DEGRADATION DURING MOLECULAR BEAM HETEROEPITAXIAL III-V MATERIAL GROWTH.....	617
<i>Laura Ding, Chaomin Zhang, Tine Uberg Nærland, Nikolai Faleev, Christiana Honsberg, Mariana I. Bertoni</i>	
ATOMIC LAYER DEPOSITED ZNO: B AS TRANSPARENT CONDUCTIVE OXIDE FOR INCREASED SHORT CIRCUIT CURRENT DENSITY IN SILICON HETEROJUNCTION SOLAR CELLS.....	624
<i>Henriette A. Gatz, Dibyashree Koushik, Jatin K. Rath, Wilhelmus M. M. Kessels, Ruud E. I. Schropp</i>	

BACK JUNCTION N-TYPE SILICON HETEROJUNCTION SOLAR CELLS WITH V₂O₅ HOLE-SELECTIVE CONTACT	633
<i>Luis G. Gerling, Gerard Masmija, Cristobal Voz, Pablo Ortega, Joaquim Puigdollers, Ramón Alcubilla</i>	
SILICON HETEROJUNCTION SOLAR CELLS COMBINING AN A-SI:H (N) ELECTRON-COLLECTOR WITH A PEDOT:PSS HOLE-COLLECTOR	638
<i>Ralf Gogolin, Dimitri Zielke, Wilfried Lövenich, Rüdiger Sauer, Jan Schmidt</i>	
A 3 TERMINAL PARALLEL CONNECTED SILICON TANDEM SOLAR CELL	644
<i>Juan. C. Jimeno, Rubén Gutierrez, Vanesa Fano, Ahmed Habib, Carlos Del Cañizo, Muhammad A. Rasool, Aloña Otaegi</i>	
“COLD” PROCESS FOR IBC C-SI SOLAR CELLS FABRICATION	652
<i>Gema López, Pablo R. Ortega, Isidro Martín, Cristóbal Voz, Albert Orpella, Ramón Alcubilla</i>	
AL_{0.2}GA_{0.8}AS SOLAR CELLS MONOLITHICALLY GROWN ON SI AND GAAS BY MBE FOR III-V/SI TANDEM DUAL-JUNCTION APPLICATIONS	661
<i>Arthur Onno, Jiang Wu, Qi Jiang, Siming Chen, Mingchu Tang, Yuri Mайданиuk, Mourad Benamara, Yuriy I. Mazur, Gregory J. Salamo, Nils-Peter Harder, Lars Oberbeck, Huiyun Liu</i>	
COMBINATION OF ADVANCED OPTICAL MODELLING WITH ELECTRICAL SIMULATION FOR PERFORMANCE EVALUATION OF PRACTICAL 4-TERMINAL PEROVSKITE/C-SI TANDEM MODULES	669
<i>Dong Zhang, Wiljan Verhees, Maarten Dörenkämper, Weiming Qiu, Klaas Bakker, Astrid Gutjahr, Sjoerd Veenstra, Robert Gehlhaar, Ulrich W. Paetzold, Wim Soppe, Ingrid Romijn, L. J. Geerligs, Tom Aernouts, Arthur Weeber</i>	

NPV WORKSHOP

STATUS OF INDUSTRIAL BACK JUNCTION N-TYPE SI SOLAR CELL DEVELOPMENT	678
<i>Stefan Bordihn, Verena Mertens, Janko Cieslak, Gregor Zimmermann, Ronny Lantzsch, Jessica Scharf, Steffen Geißler, Stefan Hörnlein, Markus Neuber, Steffen Laube, Alexandra Dietrich, Barbara Szramowski, Sascha Esefelder, Tabitha Ballmann, Björn Eisenhawer, Andreas Mohr, Martin Schaper, Kai Petter, Jörg W. Müller, Daniel J. W. Jeong, Ruiying Hao, T. Ravi</i>	
MULTIFUNCTIONAL DIELECTRIC LAYERS FOR THE FABRICATION OF ULTRA-SIMPLIFIED N-PERT C-SI SOLAR CELLS	684
<i>Raphaël Cabal, Thomas Blévin, Rémi Monna, Yannick Veschetti, Sébastien Dubois</i>	
COMPARISON OF CHARACTERIZATION TECHNIQUES FOR MEASUREMENTS OF DOPING CONCENTRATIONS IN COMPENSATED N-TYPE SILICON	691
<i>Aurélie Fauveau, Benoit Martel, Jordi Veirman, Sébastien Dubois, Anne Kaminski-Cachopo, Frédérique Ducroquet</i>	
BORON EMITTER FORMATION BY PLASMA IMMERSION ION IMPLANTATION IN N-TYPE PERT SILICON SOLAR CELLS	697
<i>Jean-François Lerat, Thibaut Desrues, Jérôme Le Perchec, Marianne Coïg, Frederic Milesi, Frédéric Mazen, Thomas Michel, Laurent Roux, Yannick Veschetti, Sébastien Dubois</i>	
TOWARD 21% EFFICIENCY NPert SOLAR CELLS WITH SELECTIVE BACK SURFACE FIELD TECHNIQUE	702
<i>Zih-Wei Peng, Po-Tsung Hsieh, Chih-Jeng Huang, Yuan-Jun Lin, Ping-Kuan Chang, Chun Kuo, Chi-Chun Li</i>	
MINORITY CARRIER LIFETIME OF N-TYPE MONO-CRYSTALLINE SILICON PRODUCED BY CONTINUOUS CZOCHRALSKI TECHNOLOGY AND ITS EFFECT ON HETERO-JUNCTION SOLAR CELLS	708
<i>Han Xu, Xiaorang Tian</i>	

PROCESS INTEGRATION

FABRICATION OF HIGH VOLTAGE MODULES BY OPTIMIZATION OF PERFORMANCES OF REDUCED AREA SILICON SOLAR CELLS	715
<i>David Bertrand, Marc Pirot, Sylvain Manuel, Anne Kaminski Cachopo, Yannick Veschetti</i>	
DEVELOPMENT OF HIGH-EFFICIENCY INDUSTRIAL P-TYPE MULTI-CRYSTALLINE PERC SOLAR CELLS WITH EFFICIENCY GREATER THAN 21%	721
<i>Weiwei Deng, Feng Ye, Zhen Xiong, Daming Chen, Wanwu Guo, Yifeng Chen, Yang Yang, Pietro P. Altermatt, Zhiqiang Feng, Pierre J. Verlinden</i>	
BACK CONTACT HETEROJUNCTION SOLAR CELLS PATTERNED BY LASER ABLATION	730
<i>Samuel Harrison, Oriol Nos, Guillaume D'Alonzo, Christine Denis, Arnau Coll, Delfina Munoz</i>	

SIMPLIFIED FABRICATION OF N-TYPE CZ-SI HIP-MWT+ SOLAR CELLS WITH 20% EFFICIENCY USING LASER STRUCTURING	738
<i>Elmar Lohmüller, Sabrina Werner, Stephan Maus, Andreas Brand, Ulrich Jäger, Jan Nekarda, Florian Clement</i>	
IMPACT OF AG PADS ON THE SERIES RESISTANCE OF PERC SOLAR CELLS	743
<i>Henning Schulte-Huxel, Robert Witteck, Paula Van Laak, Till Brendemühl, David Hinken, Karsten Bothe, Rolf Brendel</i>	
THE GLASS-GLASS MODULE USING N-TYPE BIFACIAL SOLAR CELL WITH PERT STRUCTURE AND ITS PERFORMANCE	750
<i>Qingzhu Wei, Chenyang Wu, Xiaorui Liu, Sanyang Zhang, Feng Qian, Junyu Lu, Weifei Lian, Paul Ni</i>	
<u>SILICON MATERIAL AND WAFERING TECHNOLOGIES</u>	
RECOMBINATION ACTIVITY OF 2D EXTENDED DEFECTS IN MONOLIKE SILICON	755
<i>Vanessa A. Oliveira, Hang Cheong Sio, Alexandre Faujour, Lucas Piot, Amal Chabli, Denis Camel</i>	
SIMULATION OF SPALLING WITH A NON-PLANAR BI-LAYERED INTERFACE DUE TO THE REUSE OF THE SUBSTRATE	764
<i>Irene Berardone, Jan Hensen, Verena Steckenreiter, Sarah Kajari-Schröder, Marco Paggi</i>	
UNDERSTANDING THE LIGHT-INDUCED LIFETIME DEGRADATION AND REGENERATION IN MULTICRYSTALLINE SILICON	773
<i>Dennis Bredemeier, Dominic Walter, Sandra Herlufsen, Jan Schmidt</i>	
EXCEEDING 3 MS MINORITY CARRIER LIFETIME IN N-TYPE NON-CONTACT CRUCIBLE SILICON	779
<i>Sergio Castellanos, Maulid Kivambe, Mallory A. Jensen, Douglas M. Powell, Kazuo Nakajima, Kohei Morishita, Ryota Murai, Tonio Buonassisi</i>	
SOLAR CELLS WITH 20% EFFICIENCY AND LIFETIME EVALUATION OF EPITAXIAL WAFERS	785
<i>Marion Drießen, Diana Amiri, Nena Milenkovic, Bernd Steinhauser, Stefan Lindekugel, Jan Benick, Stefan Reber, Stefan Janz</i>	
BORON-OXYGEN DEFECT FORMATION RATES AND ACTIVITY AT ELEVATED TEMPERATURES	791
<i>Phillip Hamer, Nitin Nampalli, Ziv Hameiri, Moonyong Kim, Daniel Chen, Nicholas Gorman, Brett Hallam, Malcolm Abbott, Stuart Wenham</i>	
LIGHT-INDUCED RECOVERY OF EFFECTIVE CARRIER LIFETIME IN BORON-DOPED CZOCHRALSKI SILICON AT ROOM TEMPERATURE	801
<i>Hiroaki Ichikawa, Isao Takahashi, Noritaka Usami, Katsuhiko Shirasawa, Hidetaka Takato</i>	
LIGHT-INDUCED DEGRADATION IN MULTICRYSTALLINE SILICON: THE ROLE OF COPPER	808
<i>Alessandro Inglese, Alessia Focareta, Florian Schindler, Jonas Schön, Jeanette Lindroos, Martin C. Schubert, Hele Savin</i>	
SOLAR CELL EFFICIENCY AND HIGH TEMPERATURE PROCESSING OF N-TYPE SILICON GROWN BY THE NONCONTACT CRUCIBLE METHOD	815
<i>Mallory A. Jensen, Vincenzo Lasalvia, Ashley E. Morishige, Kazuo Nakajima, Yannick Veschetti, Frederic Jay, Anis Jouini, Amanda Youssef, Paul Stradins, Tonio Buonassisi</i>	
LOW-COST KERFLESS WAFERS WITH GRADIENT DOPANT CONCENTRATION EXCEEDING 19% CELL EFFICIENCY IN PERC PRODUCTION LINE	822
<i>Ralf Jonczyk, Adam Lorenz, Ali Ersen, Jasmin Hofstetter, Kati Hübener, Klaus Duncker, Jessica Scharf, Larissa Neibergall, Kai Petter, Jörg Müller, Daniel Jeong</i>	
INFLUENCE OF AL₂O₃ AND SIN_x PASSIVATION LAYERS ON LETID	828
<i>Friederike Kersten, Johannes Heitmann, Jörg W. Müller</i>	
PLASTIC DEFORMATION AS AN ORIGIN OF DISLOCATIONS IN CAST MONO	833
<i>Andreas Krause, Lamine Sylla, Daniel Oriwol</i>	
SILICON ALLOTROPY AND CHEMISTRY AT EXTREME CONDITIONS	839
<i>Oleksandr O. Kurakevych, Yann Le Godec, Wilson A. Crichton, Timothy A. Strobel</i>	
IDENTIFICATION OF LIFETIME-LIMITING DEFECTS IN AS-RECEIVED AND HEAT TREATED SEED-END CZOCHRALSKI WAFERS	845
<i>Elénore Letty, Jordi Veirman, Wilfried Favre, Mustapha Lemiti</i>	
SILICON LUMINESCENCE SPECTRA MODELLING AND THE IMPACT OF DOPANTS	852
<i>Anyao Liu, Hieu T. Nguyen, Daniel Macdonald</i>	
INVESTIGATION OF HYDROGENATION IN N-TYPE WAFERS WITH RING- AND DISC-SHAPED DEFECT ZONES	857
<i>Petra Manshanden, Paula C. P. Bronsveld</i>	

SPATIALLY RESOLVED ANALYSIS OF LIGHT INDUCED DEGRADATION OF MULTICRYSTALLINE PERC SOLAR CELLS	867
<i>Marisa Selinger, Wolfram Kwapil, Florian Schindler, Karin Krauß, Fabian Fertig, Bernhard Michl, Wilhelm Warta, Martin C. Schubert</i>	
THERMOMECHANICAL SPALLING OF EPITAXIALLY GROWN SILICON FROM POROSIFIED SUBSTRATES	873
<i>Verena Steckenreiter, Jan Hensen, Alwina Knorr, Raphael Niepelt, Rolf Brendel, Sarah Kajari-Schröder</i>	
CHARACTERIZATION OF CU AND NI PRECIPITATES IN N- AND P-TYPE CZOCHRALSKI-GROWN SILICON BY PHOTOLUMINESCENCE	880
<i>Chang Sun, Hieu T. Nguyen, Fiacre E. Rougieux, Daniel Macdonald</i>	
THE EFFECT OF PHOSPHORUS DIFFUSION GETTERING ON RECOMBINATION AT GRAIN BOUNDARIES IN HPMC-SILICON WAFERS	886
<i>Marie S. Wiig, Krzysztof Adamczyk, Halvard Haug, Kai E. Ekstrøm, Rune Søndena</i>	
OBSERVATION OF GEOMETRY INDUCED DOPING IN THIN SI NANO-GRATING LAYERS	896
<i>Avtandil Tavkhelidze, Larissa Jangidze, Michail Mebonia, Givi Skhiladze, Doru Ursutiu, Cornel Samoila, Zaza Taliashvili, Lili Nadarata</i>	
CRITICAL NUCLEATION CONCENTRATION FOR MONOSILANE AS FUNCTION OF TEMPERATURE OBSERVED IN A FREE SPACE REACTOR	904
<i>Guro M. Wyller, Thomas J. Preston, Hallgeir Klette, Ørnulf Nordseth, Trygve T. Mongstad, Werner O. Filtvedt, Erik S. Marstein</i>	

STRUCTURING AND CONTACT FORMATION

OPTIMIZING ADHESION OF LASER STRUCTURED PLATED NI-CU CONTACTS WITH INSIGHTS FROM MICRO CHARACTERIZATION	913
<i>Andreas Büchler, Sven Kluska, Jonas Bartsch, Gisela Cimiotti, Andreas A. Brand, Martin C. Schubert, Markus Glatthaar</i>	
INFLUENCE OF CONTACT FIRING CONDITIONS ON THE CHARACTERISTICS OF BIFACIAL N-TYPE SILICON SOLAR CELLS USING AG/AL PASTES	919
<i>Alexander Frey, Susanne Fritz, Josh Engelhardt, Giso Hahn, Barbara Terheiden</i>	
CONTACTING BBR₃-BASED BORON EMITTERS WITH ALUMINIUM-FREE SCREEN-PRINTING PASTE	925
<i>Susanne Fritz, Erkan Emre, Josh Engelhardt, Stefanie Ebert, Nicolas Nowak, Jonathan Booth, Giso Hahn</i>	
HETEROJUNCTION AND PASSIVATED CONTACTS: A SIMPLE METHOD TO EXTRACT BOTH N/TCO AND P/TCO CONTACTS RESISTIVITY	932
<i>Damien Lachenal, Derk Baetzner, Walter Frammelsberger, Boris Legradic, Jérôme Meixenberger, Pierre Papet, Benjamin Strahm, Guillaume Wahli</i>	
DOUBLE PRINTING NPRT CELLS WITH NARROW CONTACT LAYERS	939
<i>Jan Lossen, Dominik Rudolph, Lejo J. Koduvelikulathu, Ricardo Carvalho, Mark P. Rossetto, Oscar Borsato, Emiliano Bortoletto, Marco Galiazzo</i>	
DOPLA SOLAR CELLS WITH TEXTURIZED FRONT SURFACE	949
<i>Isidro Martín, Arnau Coll, Gema López, Pablo R. Ortega, Juan M. López-González, Ramon Alcubilla</i>	
IBC C-SI(N) SOLAR CELLS BASED ON LASER DOPING PROCESSING FOR SELECTIVE EMITTER AND BASE CONTACT FORMATION	956
<i>Gerard Masmitja, Pablo Ortega, Isidro Martín, Gema López, Cristobal Voz, Ramón Alcubilla</i>	
THE NEW COPPER COMPOSITE OF PASTES FOR SI SOLAR CELLS FRONT ELECTRODE APPLICATION	962
<i>Piotr Panek, Robert P. Socha, Grzegorz Putynkowski, Abdelilah Slaoui</i>	
FIRING THROUGH ALUMINUM GRID PASTE FOR BIFACIAL SOLAR CELLS	971
<i>Dominik Rudolph, Thomas Buck, Andreas Teppe, Faramarz Binaie Masouleh, Rudolf Harney</i>	
MONITORING OF ADHESION FOR PLATED METALLISATION: WHY BUSBAR PULL TESTS ARE NOT SUFFICIENT	978
<i>Xi Wang, Pei-Chieh Hsiao, Wei Zhang, Xi Wang, Ben Johnston, Alex Stokes, Andreas Fell, Sachin Surve, Yuan Shengzhao, Pierre Verlinden, Alison Lennon</i>	
STUDY OF CARRIER TRANSPORT IN SILVER PASTE METALLIZED SILICON SOLAR CELLS	984
<i>Wei Wu, Christopher Chan, Mark Lewittes, Lei Zhang, Katherine Roelofs</i>	

Author Index